

# Post-deposition Catalytic-doping of Microcrystalline Silicon Thin-layer for the Application in Silicon Heterojunction Solar Cell

**Yong Liu**, Do Yun Kim, Manuel Pomaska, Yael Augarten, Andreas Lambertz,  
Florian Lentz, Jan Mock and Kaining Ding

IEK5-Photovoltaik, Forschungszentrum Jülich

# Research Center Jülich

## Finance

- Budget: 525 Mio. €
- Third Party: ~ 191 Mio. €

## Personnel

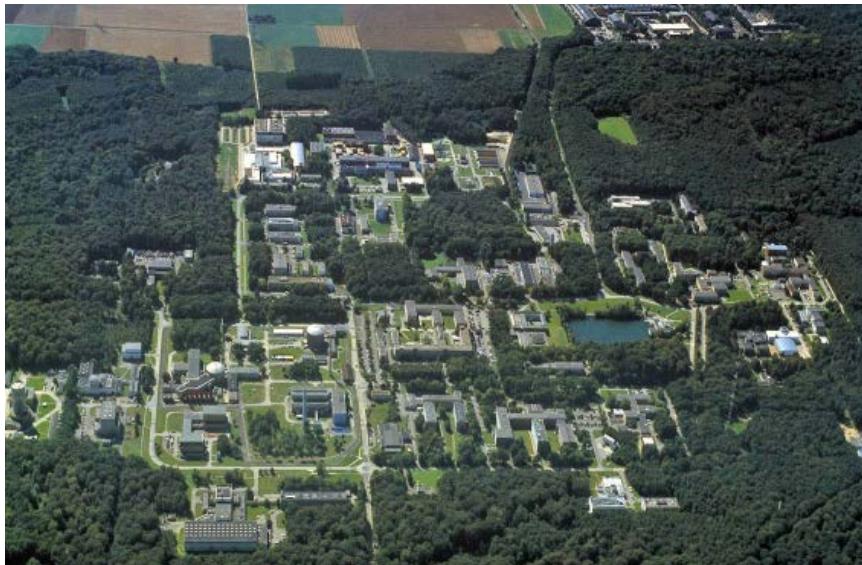
- Staff: 5.800
- scientists: 2.074 (incl. PhDs)  
+ 907 guest scientists from  
more than 45 countries

## Scientific Output

- 8.500 patents
- 192 licenses
- 1.800 articles/year

## Research Area

- Energy and Climate
- Health
- Information Technology



# IEK5-Photovoltaics

Staff: 120

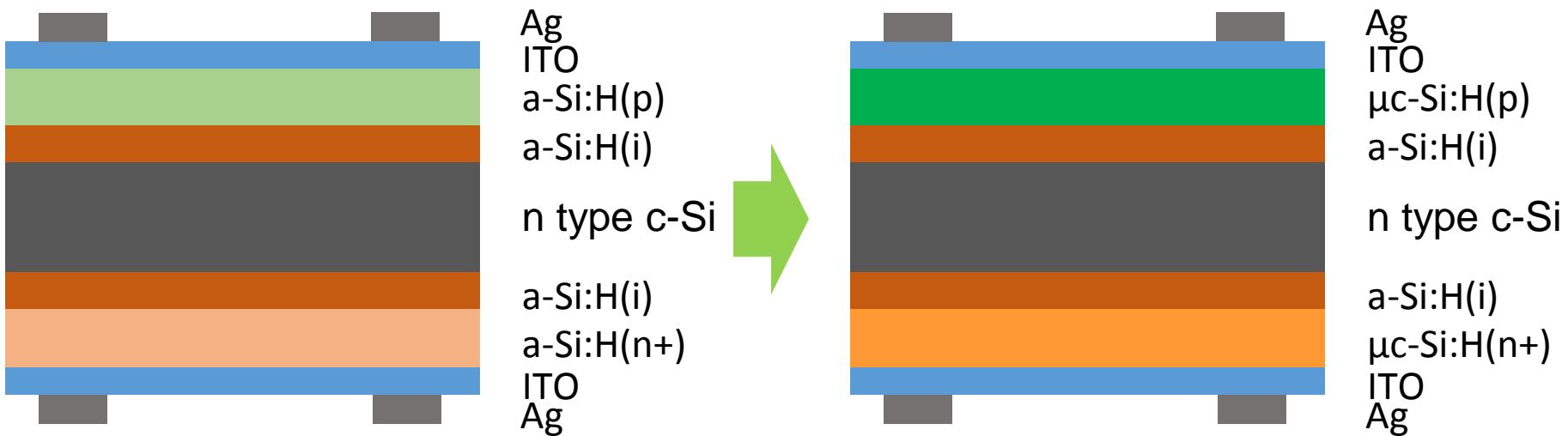
Scientists: ~25

Students : ~25

- **Thin-film technology for silicon wafer solar cells**
- Si thin-film solar cell application platform
- Novel thin-film materials and concepts
- Thin-film analytics and modeling



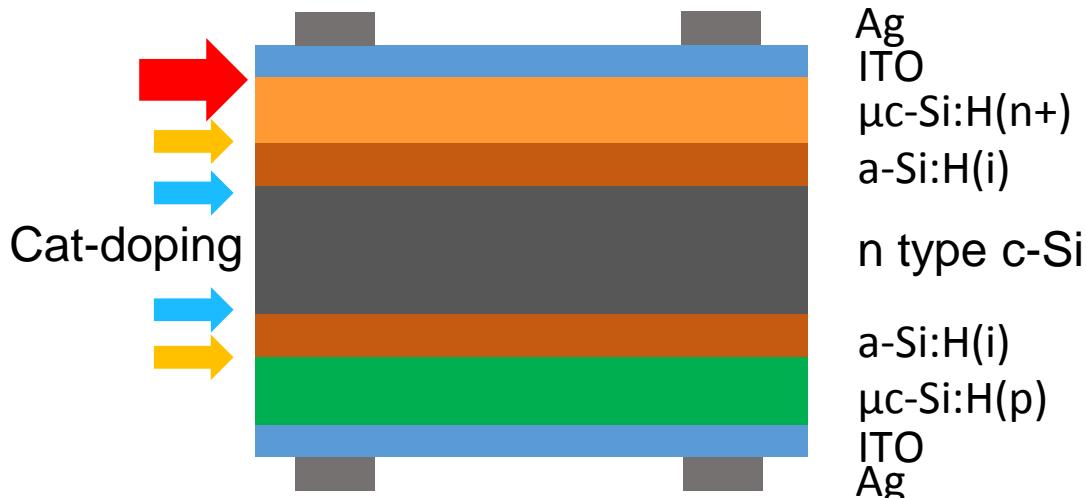
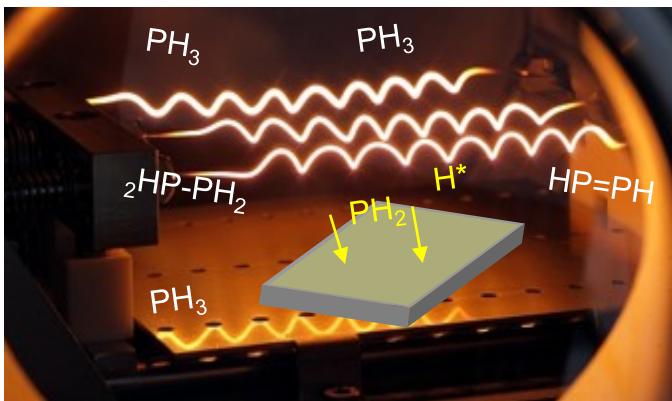
# Silicon Heterojunction (SHJ) Solar Cell



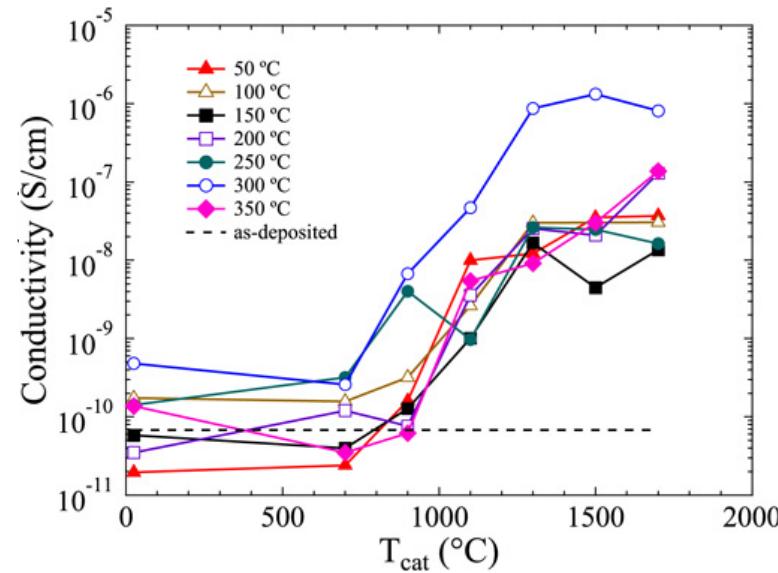
- High  $V_{OC}$  due to excellent surface passivation
- Simple, low temperature and up-scalable processes for industrial production
- Compatible with thin wafer process
- $\mu\text{c-Si:H} \rightarrow FF \uparrow$
- rear emitter  $\rightarrow J_{SC} \uparrow$
- a-Si:H passivation  $\rightarrow V_{OC} \uparrow$
- Efficiency  $\uparrow$



# Cat-doping in $\mu$ c-Si:H SHJ Solar Cell



- Low temperature
- Shallow doping depth
- Type conversion
- Improve lifetime by field effect/ H atoms
- Increase conductivity by post-doping
- Compatible with IBC solar cell process

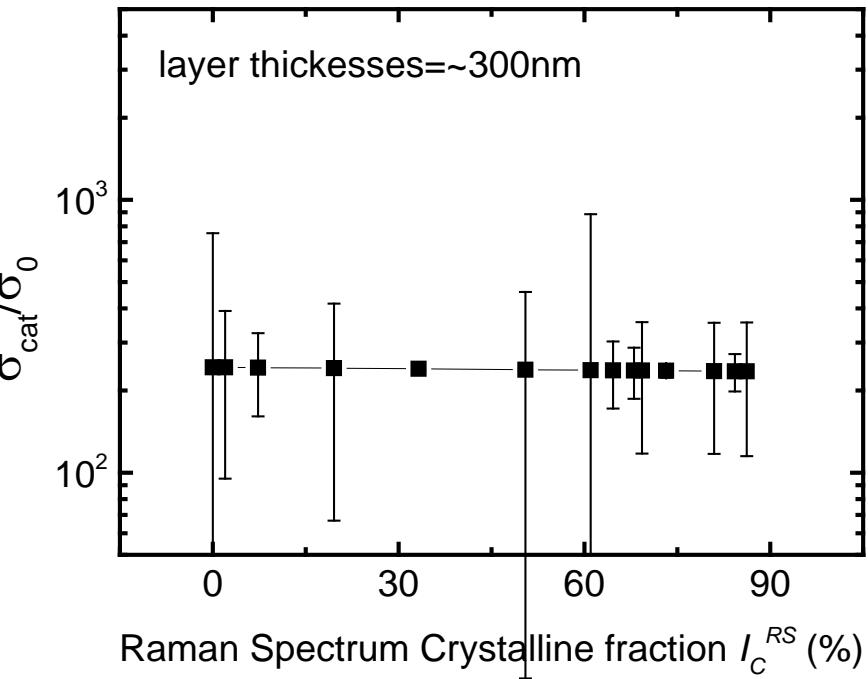
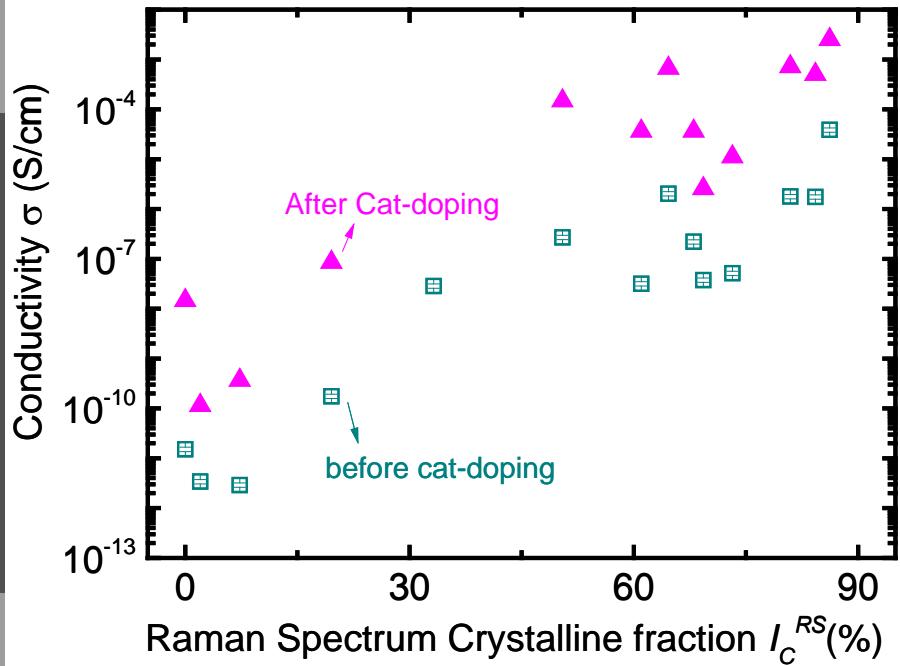


S. Tsuzaki et al., *Jpn. J. Appl. Phys.* 54, 072301 (2015)  
J. Seto et al., *Jpn. J. Appl. Phys.* 55, 04ES05 (2016)



# Cat-doping on $\mu$ c-Si:H(i)

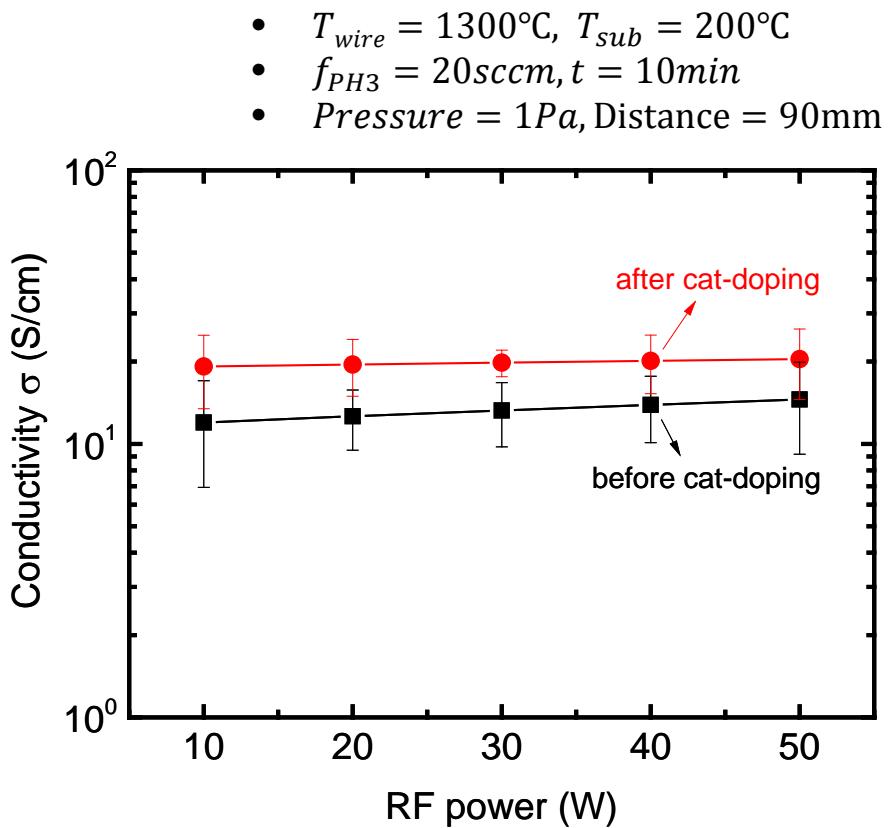
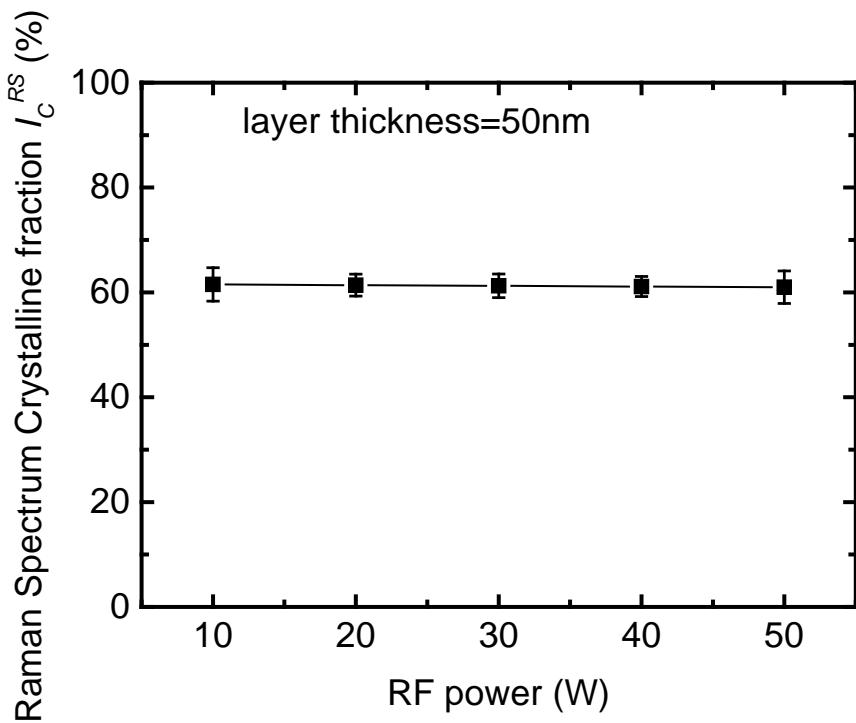
- $T_{wire} = 1300^{\circ}\text{C}$ ,  $T_{sub} = 150^{\circ}\text{C}$
- $f_{PH_3} = 20\text{sccm}$ ,  $t = 10\text{min}$
- Pressure = 1Pa, Distance = 90mm



- Cat-doping  $\rightarrow$  Conductivity  $\uparrow$
- Considering the doping depth, several orders of magnitude's improvement



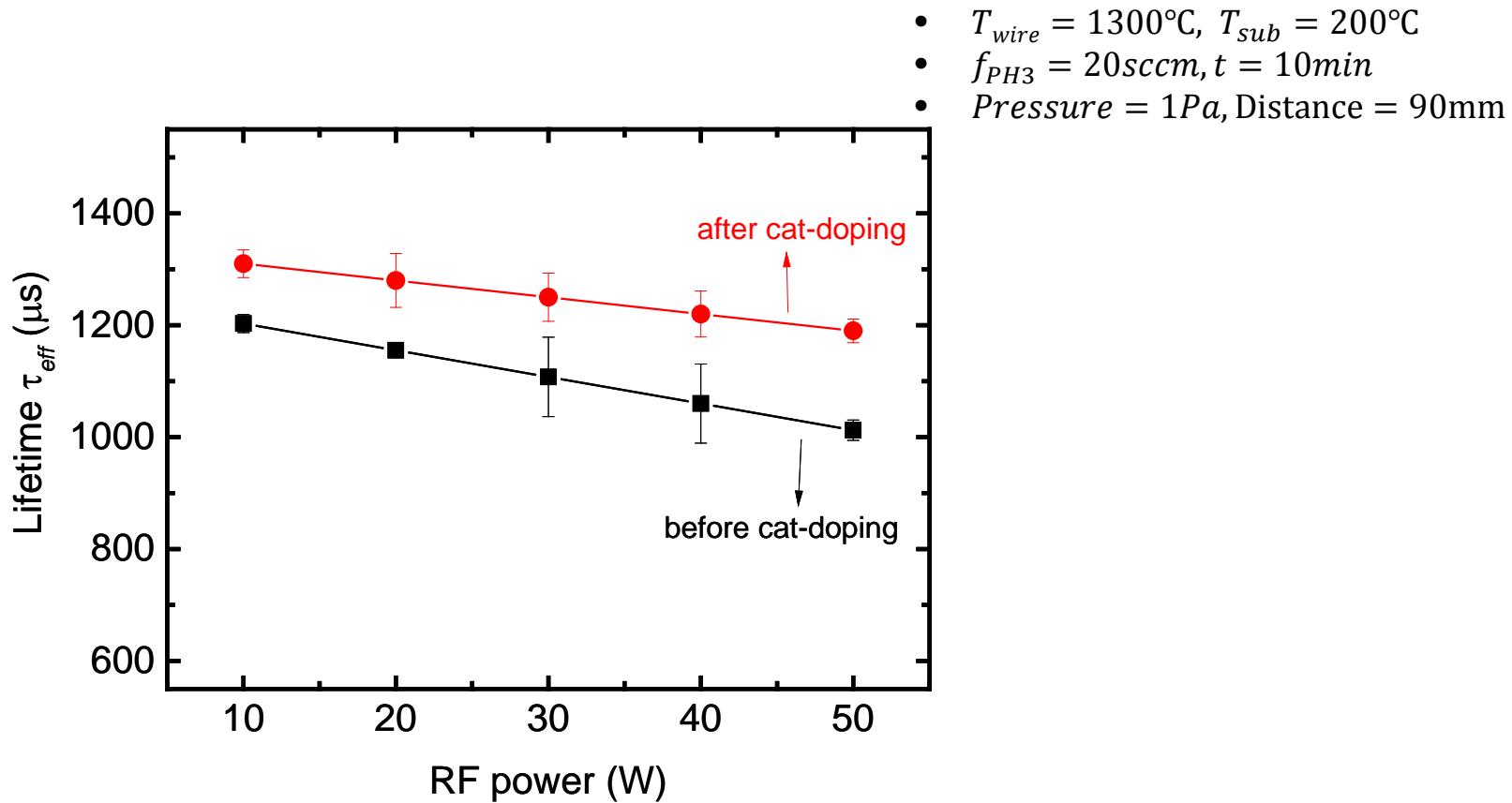
# Cat-doping on $\mu$ c-Si:H(n)



- Crystallinity stayed in a small range though the RF powers changed in a big range

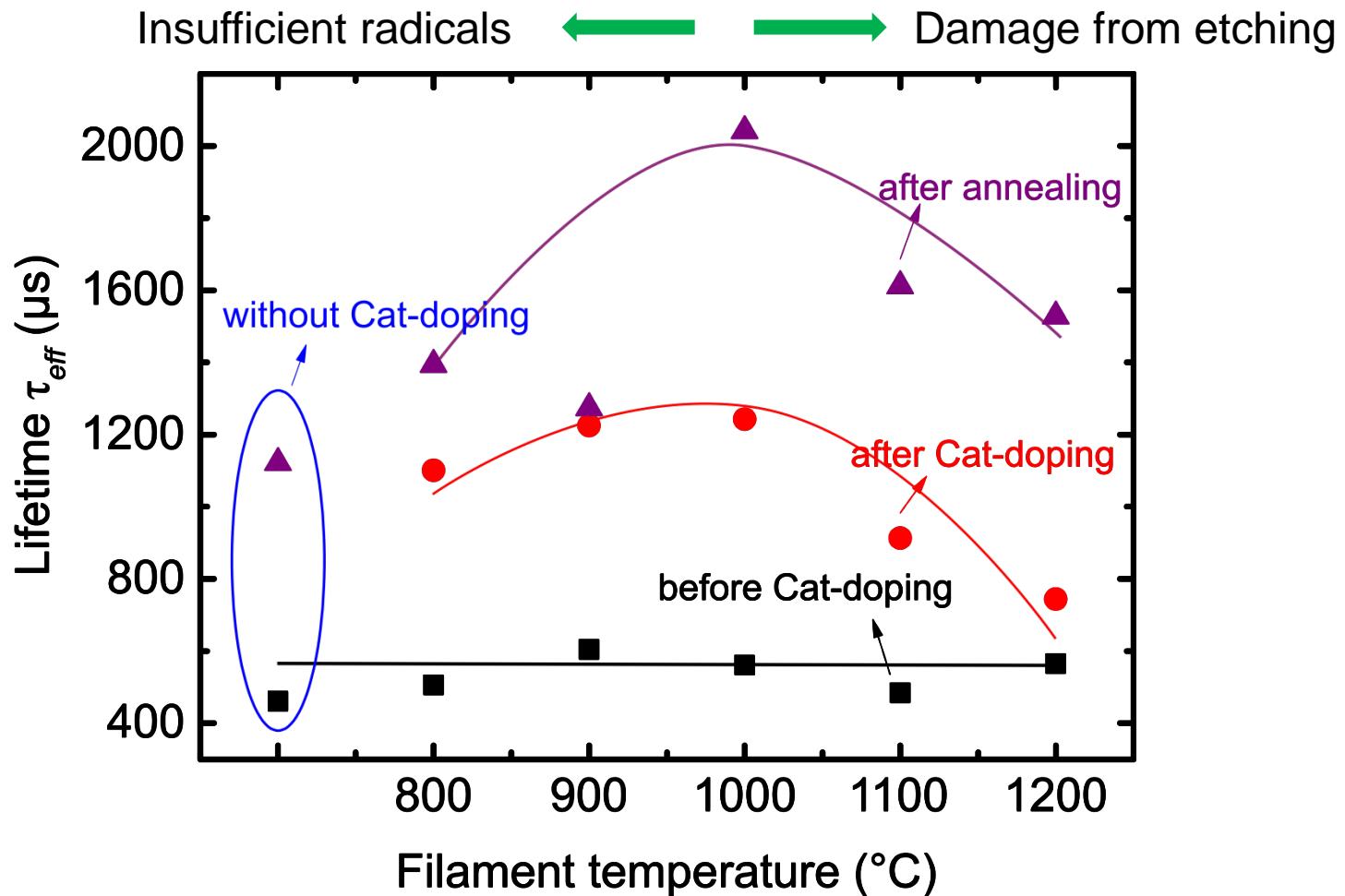
- Conductivity slightly increased after Cat-doping

# Cat-doping of $\mu$ c-Si:H(n) on wafers



- Lifetime decreases with increasing RF power probably due to ion bombardment effect
- Lifetime improved after CAT-doping probably due to the field induced passivation

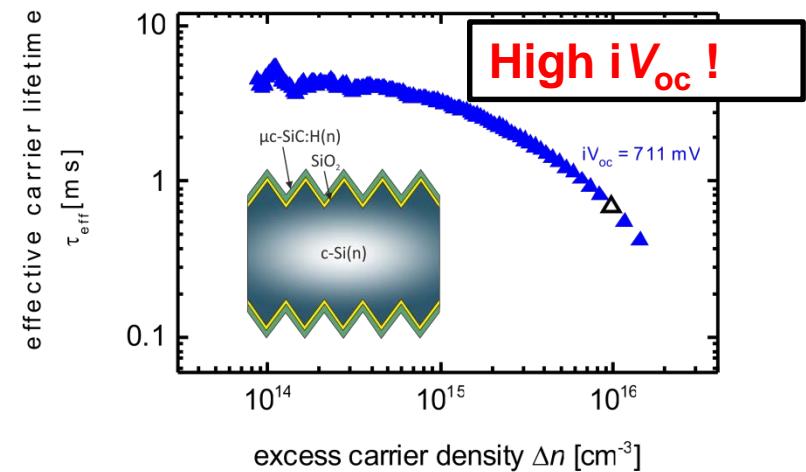
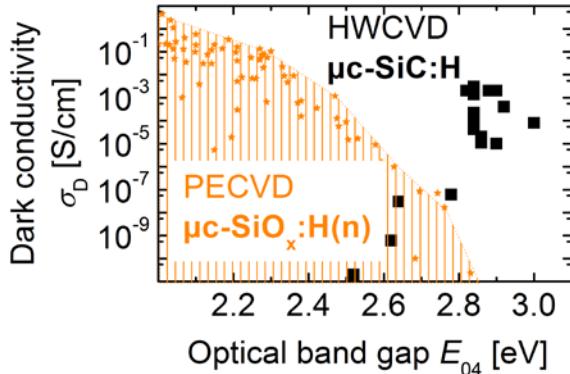
# Cat-doping with different $T_{wire}$



- Cat-doping can improve lifetime by field effect
- After annealing, more P atoms are activated

- $T_{sub} = 200^{\circ}C$
- $f_{PH_3} = 20sccm, t = 10min$
- Pressure = 1Pa, Distance = 90mm

# $\mu$ c-SiC:H(n) using HWCVD



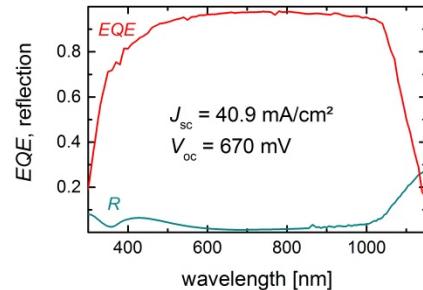
## Main material features:

- High transparency (2.6-3.0 eV)
- High refractive index (2.6-3.0)
- High electrical conductivity (up to 14 S/cm)

## Classical SHJ solar cell

Ag/ITO/ **$\mu$ c-SiC:H(n)/SiO<sub>2</sub>**/  
c-Si(n)/  
a-Si:H(i)/ $\mu$ c-SiO<sub>x</sub>:H(p)/ITO//

**High  $J_{sc}$  !**



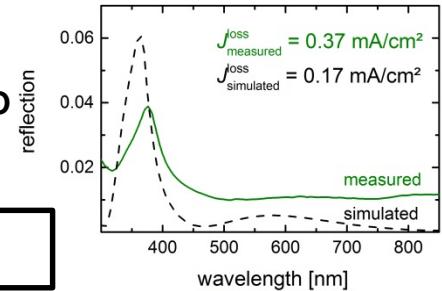
## Innovation:

Combine wet-chemical  $\text{SiO}_2$  and  $\mu$ c-SiC:H(n) for passivated and transparent front side

## IBC - SHJ solar cell

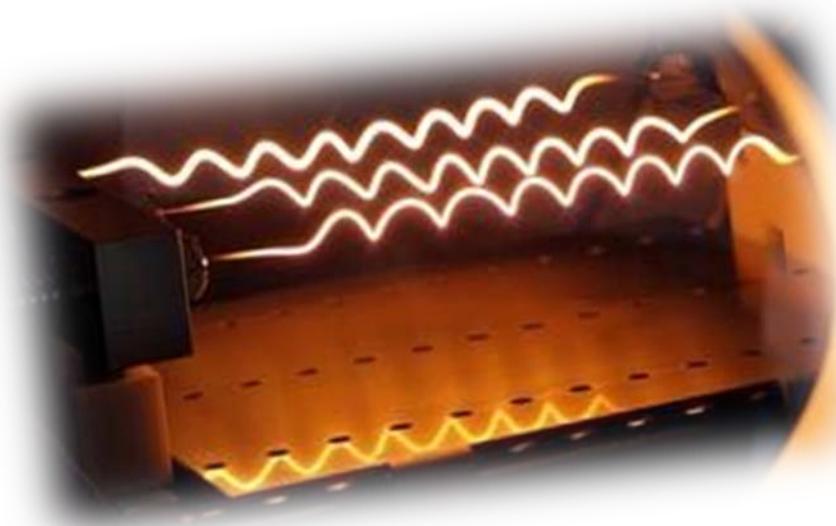
MgF<sub>2</sub>/SiN<sub>x</sub>/ **$\mu$ c-SiC:H(n)/SiO**/  
c-Si(n)/  
a-Si:H(i)/IBC

**Low reflection !**



# Summary and Outlook

- Cat-doping can dope both intrinsic and n-type  $\mu$ c-Si:H
- Cat-doping can improve the  $\tau_{eff}$  of SHJ solar cell with  $\mu$ c-Si:H and give the highest  $\tau_{eff}$  at  $900^{\circ}\text{C} \sim 1000^{\circ}\text{C}$
- Annealing can activate the P atoms which leads to further improvement
  
- P type Cat-doping of  $\mu$ c-Si:H
- Performance of cell with Cat-doping
- IBC-SHJ solar cell using Cat-doping



# Thanks

The Silicon Heterojunction Group:

**Scientific Staff:** K. Ding, A. Lambertz, D.Y. Kim, F. Lentz, L. Ding, W. Duan, O. Astakhov

**Technical Staff:** U. Gerhards, S. Lynen, M. Meyer

**PhD Students:** M. Pomaska, A. Richter, S. Nadi, Y. Liu, M. Köhler, H.M. Li

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Thank you for your attention!

